

Distributed by:

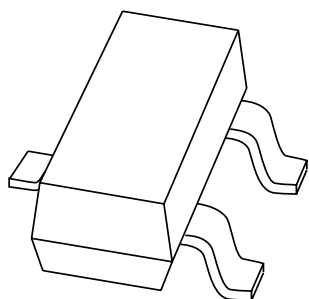
**JAMECO<sup>®</sup>**  
**ELECTRONICS**

**[www.Jameco.com](http://www.Jameco.com) ♦ 1-800-831-4242**

The content and copyrights of the attached  
material are the property of its owner.

Jameco Part Number 915198

# DATA SHEET



## **BAS19; BAS20; BAS21** General purpose diodes

Product specification  
Supersedes data of 1999 May 26

2003 Mar 20

## General purpose diodes

## BAS19; BAS20; BAS21

## FEATURES

- Small plastic SMD package
- Switching speed: max. 50 ns
- General application
- Continuous reverse voltage: max. 100 V; 150 V; 200 V
- Repetitive peak reverse voltage: max. 120 V; 200 V; 250 V
- Repetitive peak forward current: max. 625 mA.

## APPLICATIONS

- General purpose switching in e.g. surface mounted circuits.

## DESCRIPTION

The BAS19, BAS20 and BAS21 are general purpose diodes fabricated in planar technology, and encapsulated in a small SOT23 plastic SMD package.

## MARKING

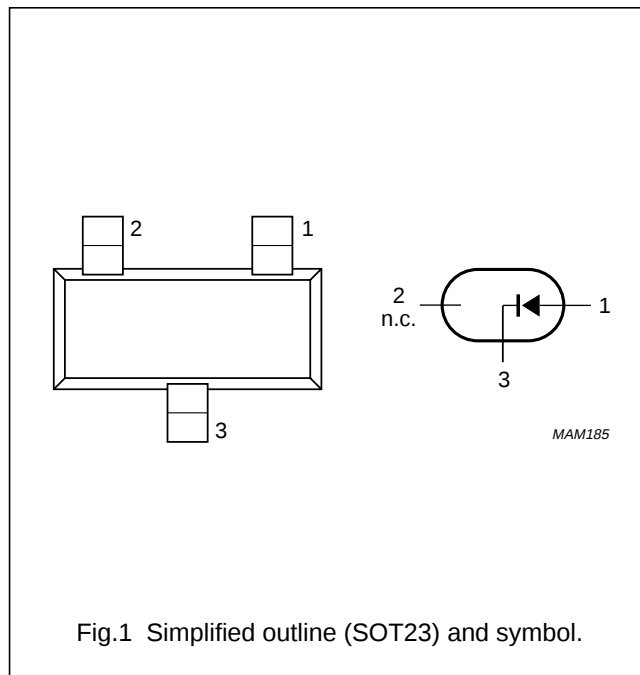
| TYPE NUMBER | MARKING CODE <sup>(1)</sup> |
|-------------|-----------------------------|
| BAS19       | JP*                         |
| BAS20       | JR*                         |
| BAS21       | JS*                         |

## Note

- \* = p: Made in Hong Kong.  
\* = t: Made in Malaysia.  
\* = W: Made in China.

## PINNING

| PIN | DESCRIPTION   |
|-----|---------------|
| 1   | anode         |
| 2   | not connected |
| 3   | cathode       |



## General purpose diodes

## BAS19; BAS20; BAS21

**LIMITING VALUES**

In accordance with the Absolute Maximum Rating System (IEC 60134).

| SYMBOL    | PARAMETER                           | CONDITIONS                                                  | MIN. | MAX. | UNIT |
|-----------|-------------------------------------|-------------------------------------------------------------|------|------|------|
| $V_{RRM}$ | repetitive peak reverse voltage     |                                                             |      |      |      |
|           | BAS19                               |                                                             | –    | 120  | V    |
|           | BAS20                               |                                                             | –    | 200  | V    |
|           | BAS21                               |                                                             | –    | 250  | V    |
| $V_R$     | continuous reverse voltage          |                                                             |      |      |      |
|           | BAS19                               |                                                             | –    | 100  | V    |
|           | BAS20                               |                                                             | –    | 150  | V    |
|           | BAS21                               |                                                             | –    | 200  | V    |
| $I_F$     | continuous forward current          | see Fig.2; note 1                                           | –    | 200  | mA   |
| $I_{FRM}$ | repetitive peak forward current     |                                                             | –    | 625  | mA   |
| $I_{FSM}$ | non-repetitive peak forward current | square wave; $T_j = 25\text{ °C}$ prior to surge; see Fig.4 |      |      |      |
|           |                                     | $t = 1\text{ }\mu\text{s}$                                  | –    | 9    | A    |
|           |                                     | $t = 100\text{ }\mu\text{s}$                                | –    | 3    | A    |
|           |                                     | $t = 10\text{ ms}$                                          | –    | 1.7  | A    |
| $P_{tot}$ | total power dissipation             | $T_{amb} = 25\text{ °C}$ ; note 1                           | –    | 250  | mW   |
| $T_{stg}$ | storage temperature                 |                                                             | –65  | +150 | °C   |
| $T_j$     | junction temperature                |                                                             | –    | 150  | °C   |

**Note**

1. Device mounted on an FR4 printed-circuit board.

## General purpose diodes

## BAS19; BAS20; BAS21

**ELECTRICAL CHARACTERISTICS**

$T_j = 25\text{ }^{\circ}\text{C}$  unless otherwise specified.

| SYMBOL   | PARAMETER                                          | CONDITIONS                                                                                                                                                                                                                                                         | MAX.                                   | UNIT                                                              |
|----------|----------------------------------------------------|--------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|----------------------------------------|-------------------------------------------------------------------|
| $V_F$    | forward voltage                                    | see Fig.3<br>$I_F = 100\text{ mA}$<br>$I_F = 200\text{ mA}$                                                                                                                                                                                                        | 1<br>1.25                              | V<br>V                                                            |
| $I_R$    | reverse current<br>BAS19<br><br>BAS20<br><br>BAS21 | see Fig.5<br>$V_R = 100\text{ V}$<br>$V_R = 100\text{ V}; T_j = 150\text{ }^{\circ}\text{C}$<br>$V_R = 150\text{ V}$<br>$V_R = 150\text{ V}; T_j = 150\text{ }^{\circ}\text{C}$<br>$V_R = 200\text{ V}$<br>$V_R = 200\text{ V}; T_j = 150\text{ }^{\circ}\text{C}$ | 100<br>100<br>100<br>100<br>100<br>100 | nA<br>$\mu\text{A}$<br>nA<br>$\mu\text{A}$<br>nA<br>$\mu\text{A}$ |
| $C_d$    | diode capacitance                                  | $f = 1\text{ MHz}; V_R = 0$ ; see Fig.6                                                                                                                                                                                                                            | 5                                      | pF                                                                |
| $t_{rr}$ | reverse recovery time                              | when switched from $I_F = 30\text{ mA}$ to<br>$I_R = 30\text{ mA}; R_L = 100\text{ }\Omega$ ; measured at<br>$I_R = 3\text{ mA}$ ; see Fig.8                                                                                                                       | 50                                     | ns                                                                |

**THERMAL CHARACTERISTICS**

| SYMBOL         | PARAMETER                                     | CONDITIONS | VALUE | UNIT |
|----------------|-----------------------------------------------|------------|-------|------|
| $R_{th\ j-tp}$ | thermal resistance from junction to tie-point |            | 330   | K/W  |
| $R_{th\ j-a}$  | thermal resistance from junction to ambient   | note 1     | 500   | K/W  |

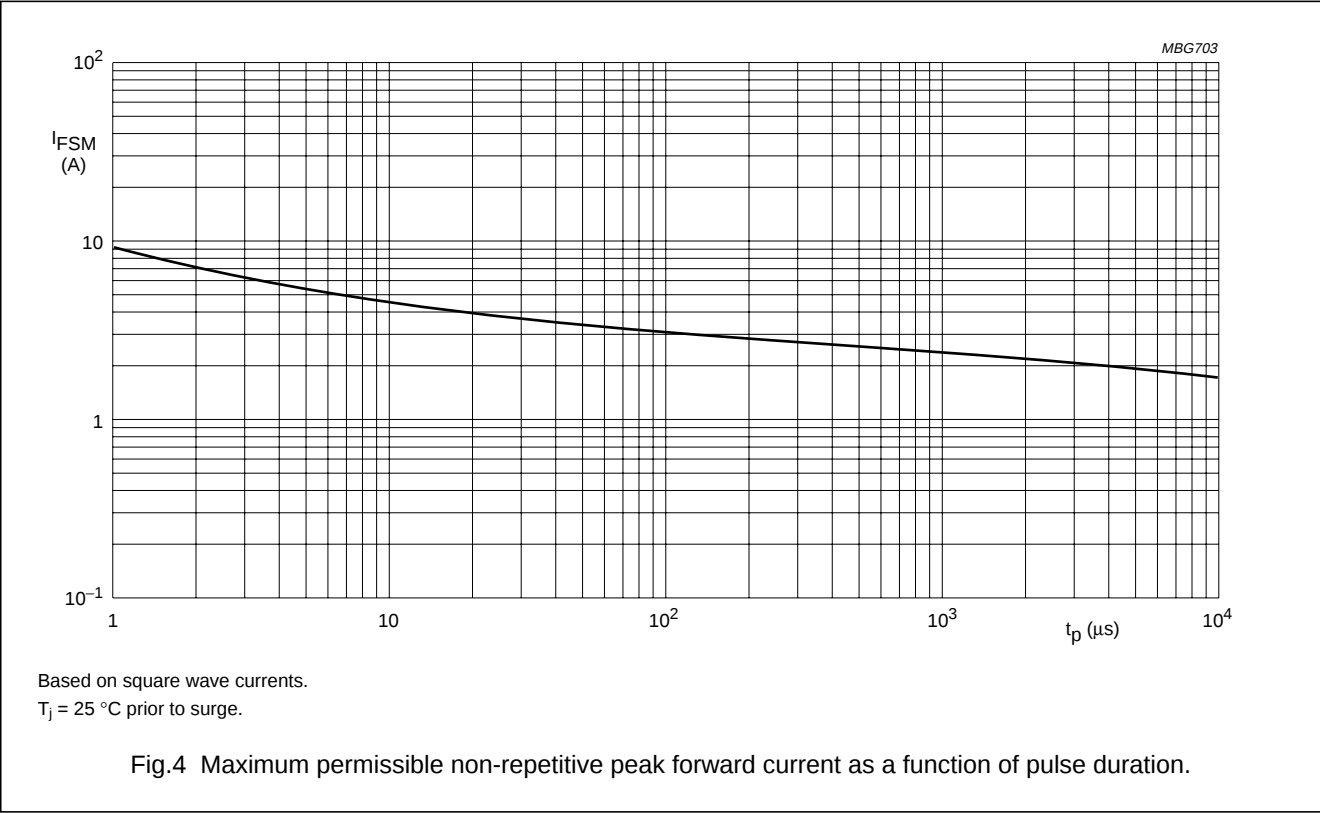
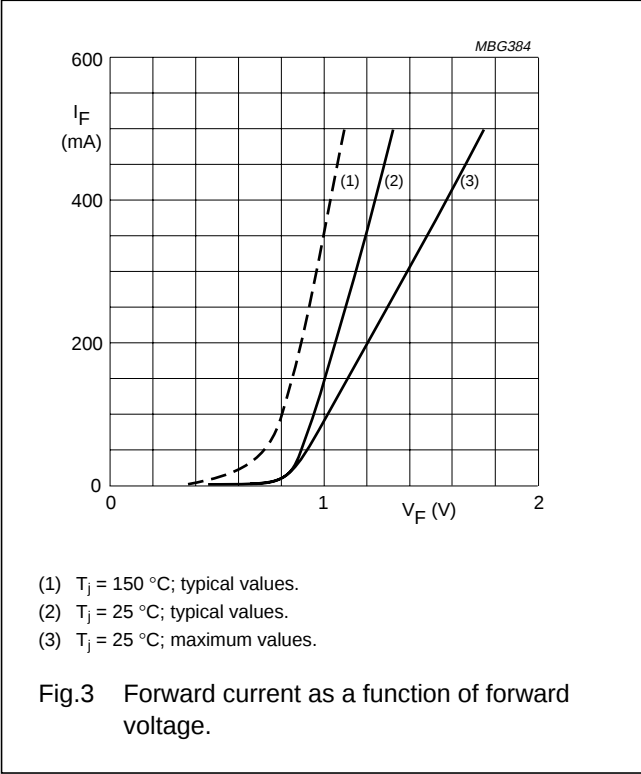
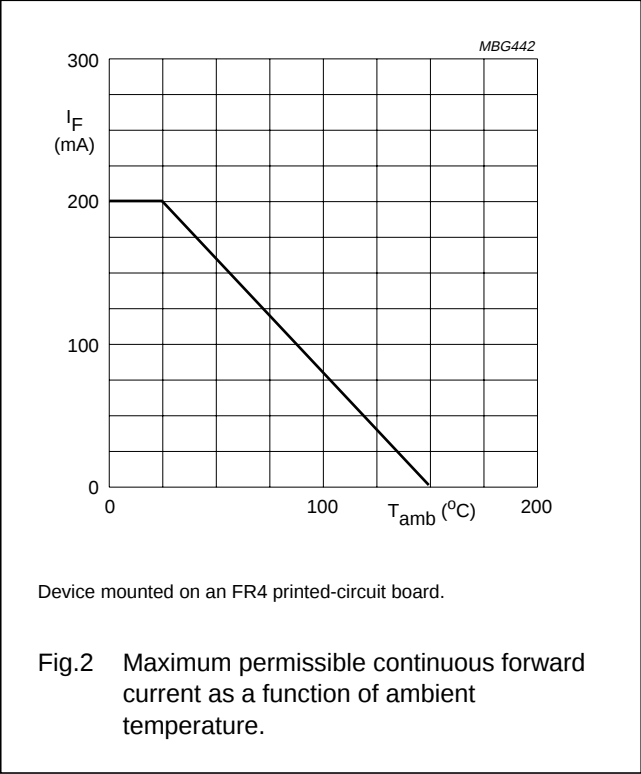
**Note**

1. Device mounted on an FR4 printed-circuit board.

General purpose diodes

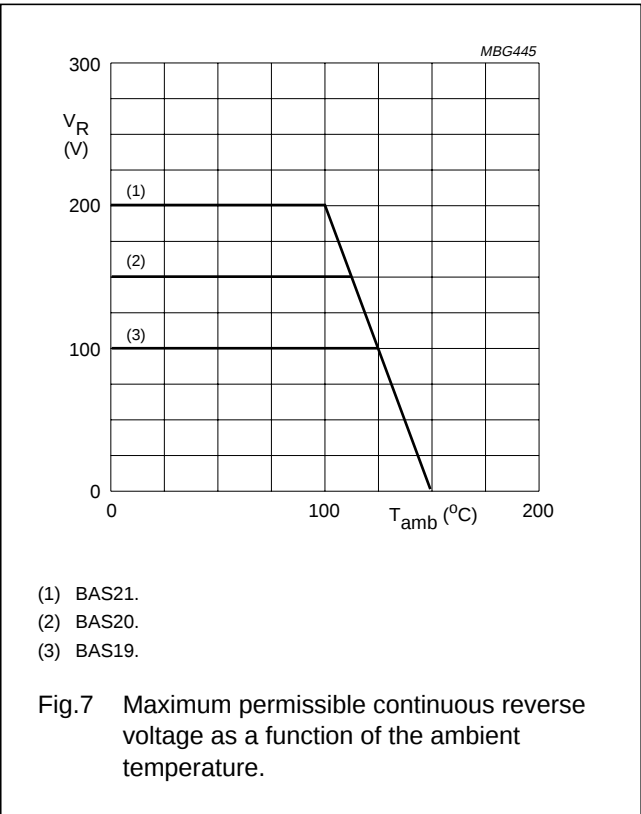
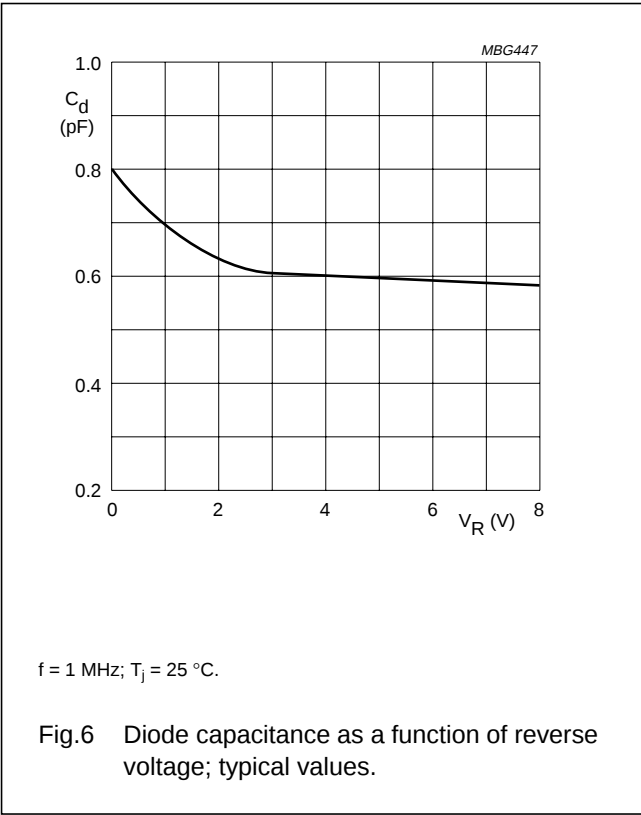
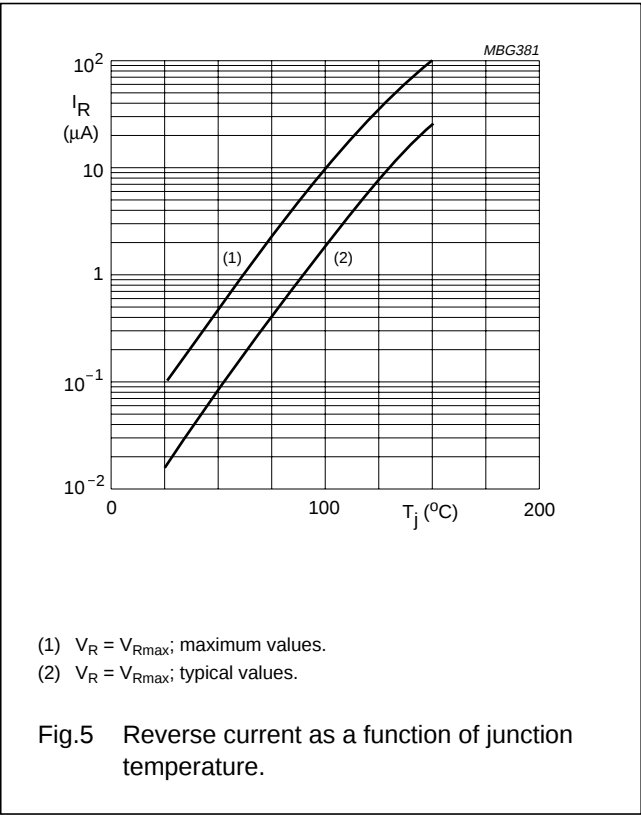
BAS19; BAS20; BAS21

GRAPHICAL DATA



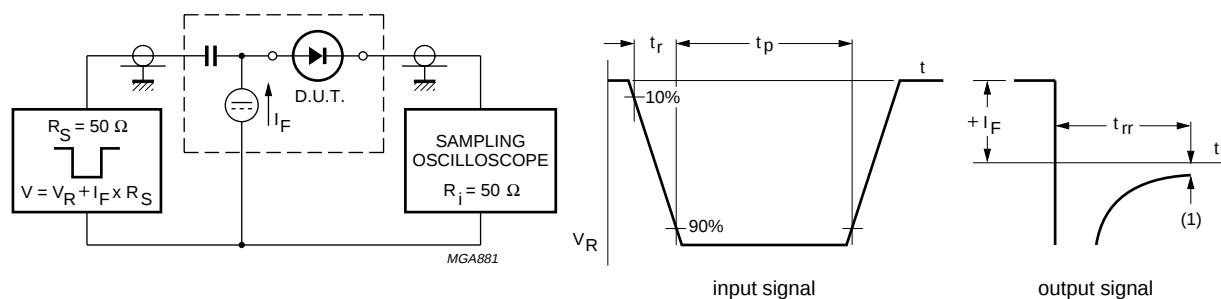
General purpose diodes

BAS19; BAS20; BAS21



## General purpose diodes

## BAS19; BAS20; BAS21



(1)  $I_R = 3 \text{ mA}$ .

Fig.8 Reverse recovery voltage test circuit and waveforms.

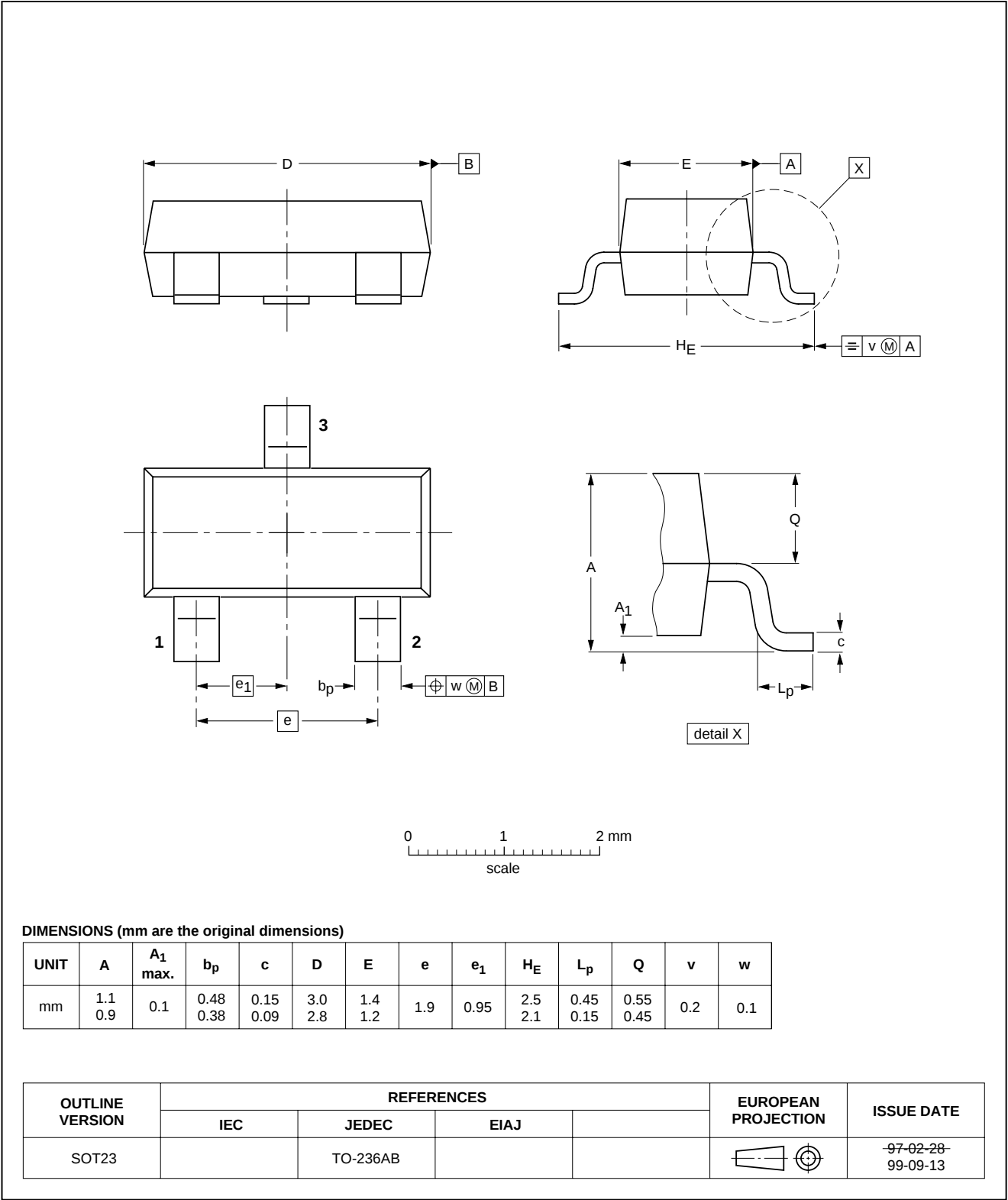
General purpose diodes

BAS19; BAS20; BAS21

PACKAGE OUTLINE

Plastic surface mounted package; 3 leads

SOT23



## General purpose diodes

## BAS19; BAS20; BAS21

## DATA SHEET STATUS

| LEVEL | DATA SHEET STATUS <sup>(1)</sup> | PRODUCT STATUS <sup>(2)(3)</sup> | DEFINITION                                                                                                                                                                                                                                                                                     |
|-------|----------------------------------|----------------------------------|------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| I     | Objective data                   | Development                      | This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.                                                                                                    |
| II    | Preliminary data                 | Qualification                    | This data sheet contains data from the preliminary specification. Supplementary data will be published at a later date. Philips Semiconductors reserves the right to change the specification without notice, in order to improve the design and supply the best possible product.             |
| III   | Product data                     | Production                       | This data sheet contains data from the product specification. Philips Semiconductors reserves the right to make changes at any time in order to improve the design, manufacturing and supply. Relevant changes will be communicated via a Customer Product/Process Change Notification (CPCN). |

## Notes

1. Please consult the most recently issued data sheet before initiating or completing a design.
2. The product status of the device(s) described in this data sheet may have changed since this data sheet was published. The latest information is available on the Internet at URL <http://www.semiconductors.philips.com>.
3. For data sheets describing multiple type numbers, the highest-level product status determines the data sheet status.

## DEFINITIONS

**Short-form specification** — The data in a short-form specification is extracted from a full data sheet with the same type number and title. For detailed information see the relevant data sheet or data handbook.

**Limiting values definition** — Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 60134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

**Application information** — Applications that are described herein for any of these products are for illustrative purposes only. Philips Semiconductors make no representation or warranty that such applications will be suitable for the specified use without further testing or modification.

## DISCLAIMERS

**Life support applications** — These products are not designed for use in life support appliances, devices, or systems where malfunction of these products can reasonably be expected to result in personal injury. Philips Semiconductors customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Philips Semiconductors for any damages resulting from such application.

**Right to make changes** — Philips Semiconductors reserves the right to make changes in the products - including circuits, standard cells, and/or software - described or contained herein in order to improve design and/or performance. When the product is in full production (status 'Production'), relevant changes will be communicated via a Customer Product/Process Change Notification (CPCN). Philips Semiconductors assumes no responsibility or liability for the use of any of these products, conveys no licence or title under any patent, copyright, or mask work right to these products, and makes no representations or warranties that these products are free from patent, copyright, or mask work right infringement, unless otherwise specified.

---

General purpose diodes

BAS19; BAS20; BAS21

---

**NOTES**

---

General purpose diodes

BAS19; BAS20; BAS21

---

**NOTES**

# ***Philips Semiconductors – a worldwide company***

## **Contact information**

For additional information please visit <http://www.semiconductors.philips.com>. Fax: **+31 40 27 24825**

For sales offices addresses send e-mail to: [sales.addresses@www.semiconductors.philips.com](mailto:sales.addresses@www.semiconductors.philips.com).

© Koninklijke Philips Electronics N.V. 2003

SCA75

All rights are reserved. Reproduction in whole or in part is prohibited without the prior written consent of the copyright owner.

The information presented in this document does not form part of any quotation or contract, is believed to be accurate and reliable and may be changed without notice. No liability will be accepted by the publisher for any consequence of its use. Publication thereof does not convey nor imply any license under patent- or other industrial or intellectual property rights.

Printed in The Netherlands

613514/04/pp12

Date of release: 2003 Mar 20

Document order number: 9397 750 10961

*Let's make things better.*

**Philips  
Semiconductors**



**PHILIPS**